

# Yuji Noguchi

## List of Publications by Year in Descending Order

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The third column is the impact factor (IF) of the journal, and the fourth column is the number of citations of the article.

200  
papers

4,897  
citations

37  
h-index

65  
g-index

209  
ext. papers

5,283  
ext. citations

2.1  
avg, IF

5.54  
L-index

#	Paper	IF	Citations
200	Order-disorder nature and elastic anomaly of successive phase transition of $(K_{0.5}Na_{0.5})NbO_3$ proved by broadband Brillouin scattering. <i>Ferroelectrics</i> , <b>2022</b> , 586, 2-9	0.6	
199	Defect chemistry in perovskite ferroelectrics: History, present status, and future prospects. <i>Journal of the Ceramic Society of Japan</i> , <b>2021</b> , 129, 271-285	1	1
198	Ferroelectric photovoltaic tensor in visible-light-active Fe-doped $BaTiO_3$ single crystals. <i>Japanese Journal of Applied Physics</i> , <b>2021</b> , 60, SFFA01	1.4	0
197	Lattice engineering by Sr-substitution leads to high piezoelectric performance of $(Sr_xCa_{1-x})_3TaAl_3Si_2O_{14}$ single crystals. <i>Journal of Alloys and Compounds</i> , <b>2021</b> , 851, 156860	5.7	1
196	Domain-wall photovoltaic effect in Fe-doped $BaTiO_3$ single crystals. <i>Journal of Applied Physics</i> , <b>2021</b> , 129, 084101	2.5	2
195	Polarization and Dielectric Properties of $BiFeO_3$ - $BaTiO_3$ Superlattice-Structured Ferroelectric Films. <i>Nanomaterials</i> , <b>2021</b> , 11,	5.4	2
194	Nanoscale structural analysis of $Bi_{0.5}Na_{0.5}TiO_3$ in high-temperature phases. <i>Japanese Journal of Applied Physics</i> , <b>2021</b> , 60, SFFA08	1.4	0
193	Enhanced photovoltaic effects in ferroelectric solid solution thin films with nanodomains. <i>Applied Physics Letters</i> , <b>2020</b> , 116, 132901	3.4	8
192	Nanoscale structural analysis of $Bi_{0.5}Na_{0.5}TiO_3$ . <i>Japanese Journal of Applied Physics</i> , <b>2020</b> , 59, SPPA01	1.4	10
191	Successive redox-mediated visible-light ferrophotovoltaics. <i>Nature Communications</i> , <b>2020</b> , 11, 966	17.4	14
190	Visualization of spontaneous electronic polarization in Pb ion of ferroelectric $PbTiO_3$ by synchrotron-radiation x-ray diffraction. <i>Applied Physics Letters</i> , <b>2020</b> , 117, 252905	3.4	6
189	Nanoscale structural analysis of $Pb(MgNb)O_3$ . <i>Journal of Physics Condensed Matter</i> , <b>2020</b> ,	1.8	1
188	Local structure analysis of $PbTiO_3$ in high-temperature cubic phase. <i>Ferroelectrics</i> , <b>2019</b> , 538, 57-62	0.6	3
187	Ferroelectrics with a controlled oxygen-vacancy distribution by design. <i>Scientific Reports</i> , <b>2019</b> , 9, 4225	4.9	23
186	Ferroelectric-mediated morphotropic phase boundaries in Bi-based polar perovskites. <i>Scientific Reports</i> , <b>2019</b> , 9, 4087	4.9	6
185	Composition-driven structural variation in ferroelectric phase of $(Bi_{1/2}Na_{1/2})TiO_3$ - $Ba(Mg_{1/3}Nb_{2/3})O_3$ . <i>Japanese Journal of Applied Physics</i> , <b>2019</b> , 58, SLLA04	1.4	1
184	Uncovering ferroelectric polarization in tetragonal $(BiK)TiO_3$ - $(BiNa)TiO_3$ single crystals. <i>Scientific Reports</i> , <b>2019</b> , 9, 19275	4.9	2

183 Development of Novel Ferroelectric Materials **2018**, 651-654

182 Control of misfit strain in ferroelectric BaTiO<sub>3</sub> thin-film capacitors with SrRuO<sub>3</sub>-based electrodes on (Ba, Sr)TiO<sub>3</sub>-buffered SrTiO<sub>3</sub> substrates. *Applied Physics Letters*, **2018**, 113, 012903 3.4 7

181 Successive phase transition of lead-free ferroelectric sodium potassium niobate crystals studied by Raman scattering. *Ferroelectrics*, **2018**, 532, 183-189 0.6 2

180 Crystal structure and ferroelectric polarization of tetragonal (Bi<sup>1/2</sup>Na<sup>1/2</sup>)TiO<sub>3</sub>–BaTiO<sub>3</sub>. *Japanese Journal of Applied Physics*, **2018**, 57, 11UD05 1.4 4

179 Fabrication and characterization of (Ba, Sr)RuO<sub>3</sub> ceramic targets and thin films for ferroelectric BaTiO<sub>3</sub> thin-film capacitors. *AIP Advances*, **2018**, 8, 115135 1.5 1

178 Piezoelectric Ca<sub>3</sub>TaAl<sub>3</sub>Si<sub>2</sub>O<sub>14</sub> (CTAS): High quality 2-in. single-crystal growth and electro-elastic properties from room to high (650 °C) temperature. *Journal of Crystal Growth*, **2018**, 501, 38-42 1.6 5

177 Gap-state engineering of visible-light-active ferroelectrics for photovoltaic applications. *Nature Communications*, **2017**, 8, 207 17.4 91

176 Resistivity and piezoelectric properties of Ca<sub>3</sub>TaGa<sub>1.5</sub>Al<sub>1.5</sub>Si<sub>2</sub>O<sub>14</sub> single crystals for high temperature sensors. *RSC Advances*, **2017**, 7, 56697-56703 3.7 2

175 Enhanced polarization properties of ferroelectric (Bi<sup>1/2</sup>Na<sup>1/2</sup>)TiO<sub>3</sub>–Ba(Mg<sup>1/3</sup>Nb<sup>2/3</sup>)O<sub>3</sub> single crystals grown under high-pressure oxygen atmosphere. *Journal of the Ceramic Society of Japan*, **2017**, 125, 463-467 1 2

174 Influence of growth conditions on the optical, electrical resistivity and piezoelectric properties of Ca<sub>3</sub>TaGa<sub>3</sub>Si<sub>2</sub>O<sub>14</sub> single crystals. *Journal of the Ceramic Society of Japan*, **2016**, 124, 523-527 1 14

173 Strong interaction between ferroelectric polarization and oxygen vacancy in BiFeO<sub>3</sub> thin film capacitors. *Journal of the Ceramic Society of Japan*, **2016**, 124, 634-638 1 6

172 Influence of Oxygen Partial Pressure during Growth on Optical and Electrical Properties of Ca<sub>3</sub>TaAl<sub>3</sub>Si<sub>2</sub>O<sub>14</sub> Single Crystals. *Crystal Growth and Design*, **2016**, 16, 2151-2156 3.5 13

171 Photon energy dependence of photovoltaic properties in ferroelectric BiFeO<sub>3</sub> thin-film capacitors. *Transactions of the Materials Research Society of Japan*, **2016**, 41, 201-204 0.2

170 Electronic Origin of Defect States in Fe-Doped LiNbO<sub>3</sub> Ferroelectrics. *Advances in Condensed Matter Physics*, **2016**, 2016, 1-10 1 11

169 Temperature dependence of electrical resistivity, dielectric and piezoelectric properties of Ca<sub>3</sub>TaGa<sub>3</sub>–Al<sub>x</sub>Si<sub>2</sub>O<sub>14</sub> single crystals as a function of Al content. *Journal of Alloys and Compounds*, **2016**, 687, 797-803 5.7 9

168 Bulk and domain-wall effects in ferroelectric photovoltaics. *Physical Review B*, **2016**, 94, 3.3 32

167 Polarization twist in perovskite ferroelectrics. *Scientific Reports*, **2016**, 6, 32216 4.9 21

166 Cooperative effect of oxygen-vacancy-rich layer and ferroelectric polarization on photovoltaic properties in BiFeO<sub>3</sub> thin film capacitors. *Applied Physics Letters*, **2016**, 108, 032901 3.4 32

165	Enhanced polarization properties of ferroelectric AgNbO <sub>3</sub> single crystals grown by Czochralski method under high-pressure oxygen atmosphere. <i>Japanese Journal of Applied Physics</i> , <b>2016</b> , 55, 10TB03	1.4	3
164	Crystal structure and polarization hysteresis properties of ferroelectric BaTiO <sub>3</sub> thin-film capacitors on (Ba,Sr)TiO <sub>3</sub> -buffered substrates. <i>Japanese Journal of Applied Physics</i> , <b>2016</b> , 55, 10TA03	1.4	4
163	Local polarization switching in epitaxial thin films of ferroelectric (Bi <sub>1/2</sub> Na <sub>1/2</sub> )TiO <sub>3</sub> Peer review under responsibility of The Ceramic Society of Japan and the Korean Ceramic Society. View all notes. <i>Journal of Asian Ceramic Societies</i> , <b>2015</b> , 3, 160-163	2.4	7
162	Ferroelectric phase in the (Bi <sub>1/2</sub> Na <sub>1/2</sub> )TiO <sub>3</sub> Ba(Mg <sub>1/3</sub> Nb <sub>2/3</sub> )O <sub>3</sub> system. <i>Japanese Journal of Applied Physics</i> , <b>2015</b> , 54, 10NC05	1.4	10
161	Heavy Mn-doping effect on spontaneous polarization in ferroelectric BiFeO <sub>3</sub> thin films. <i>Japanese Journal of Applied Physics</i> , <b>2015</b> , 54, 10NA03	1.4	18
160	Switchable diode-effect mechanism in ferroelectric BiFeO <sub>3</sub> thin film capacitors. <i>Journal of Applied Physics</i> , <b>2015</b> , 118, 114101	2.5	33
159	Giant photovoltaic effect of ferroelectric domain walls in perovskite single crystals. <i>Scientific Reports</i> , <b>2015</b> , 5, 14741	4.9	52
158	Enhanced photovoltaic currents in strained Fe-doped LiNbO <sub>3</sub> films. <i>Physica Status Solidi (A) Applications and Materials Science</i> , <b>2015</b> , 212, 2968-2974	1.6	18
157	Electrical conduction mechanism in BiFeO <sub>3</sub> -based ferroelectric thin-film capacitors: Impact of Mn doping Peer review under responsibility of The Ceramic Society of Japan and the Korean Ceramic Society. View all notes. <i>Journal of Asian Ceramic Societies</i> , <b>2015</b> , 3, 426-431	2.4	11
156	Non-180° polarization rotation of ferroelectric (Bi <sub>0.5</sub> Na <sub>0.5</sub> )TiO <sub>3</sub> single crystals under electric field. <i>Physical Review B</i> , <b>2014</b> , 89,	3.3	28
155	Polarization properties and crystal structures of ferroelectric (Ba,Ca)TiO <sub>3</sub> single crystals. <i>Journal of Advanced Dielectrics</i> , <b>2014</b> , 04, 1450003	1.3	6
154	Polarization degradation and oxygen-vacancy rearrangement in Mn-doped BaTiO <sub>3</sub> ferroelectric ceramics. <i>Journal of the Ceramic Society of Japan</i> , <b>2014</b> , 122, 373-380	1	6
153	Polarization Rotation and Monoclinic Distortion in Ferroelectric (Bi <sub>0.5</sub> Na <sub>0.5</sub> )TiO <sub>3</sub> BaTiO <sub>3</sub> Single Crystals under Electric Fields. <i>Crystals</i> , <b>2014</b> , 4, 273-295	2.3	21
152	Polarization-switching dynamics and microstructures of ferroelectric (Bi <sub>0.5</sub> Na <sub>0.5</sub> )TiO <sub>3</sub> single crystals. <i>Journal of the Korean Physical Society</i> , <b>2013</b> , 62, 1035-1040	0.6	2
151	Synchrotron radiation analyses of domain switching behaviors for ferroelectric BaTiO <sub>3</sub> single crystals under electric fields. <i>Journal of the Korean Physical Society</i> , <b>2013</b> , 62, 1046-1050	0.6	
150	Enhanced polarization switching in ferroelectric Bi <sub>0.5</sub> Na <sub>0.5</sub> TiO <sub>3</sub> single crystals by defect control. <i>Physica Status Solidi (A) Applications and Materials Science</i> , <b>2013</b> , 210, 791-795	1.6	6
149	Crystal Structures and Surface Morphologies of LaGaO <sub>3</sub> -Based Epitaxial Thin Films Grown by a Pulse Laser Deposition Method. <i>Key Engineering Materials</i> , <b>2013</b> , 582, 153-156	0.4	1
148	Damped soft phonons and diffuse scattering in (Bi <sub>1/2</sub> Na <sub>1/2</sub> )TiO <sub>3</sub> . <i>Physical Review B</i> , <b>2013</b> , 87,	3.3	28

147	Synchrotron Radiation Analyses of Domain Switching and Lattice Strain Behaviors for Ferroelectric (Bi <sub>0.5</sub> Na <sub>0.5</sub> )TiO <sub>3</sub> Single Crystals under Electric Fields. <i>Ferroelectrics</i> , <b>2013</b> , 443, 1-7	0.6	7
146	Leakage Current and Polarization Properties of (Bi <sub>0.5</sub> Na <sub>0.5</sub> )TiO <sub>3</sub> -BaTiO <sub>3</sub> Single Crystals. <i>Key Engineering Materials</i> , <b>2013</b> , 582, 96-99	0.4	1
145	Growth and Ferroelectric/Piezoelectric Properties of (K,Na)(Nb,Ta)O <sub>3</sub> Ferroelectric Single Crystals. <i>Key Engineering Materials</i> , <b>2013</b> , 566, 64-67	0.4	2
144	Domain Dynamics under Unipolar Electric Fields for BaTiO <sub>3</sub> Single Crystals. <i>Key Engineering Materials</i> , <b>2013</b> , 582, 40-43	0.4	
143	Crystal Structural Analyses of Ferroelectric Tetragonal (Bi <sub>1/2</sub> Na <sub>1/2</sub> )TiO <sub>3</sub> BaTiO <sub>3</sub> Powders and Single Crystals. <i>Japanese Journal of Applied Physics</i> , <b>2013</b> , 52, 09KD01	1.4	21
142	Polarization Switching Dynamics of Ferroelectric (Bi <sub>0.5</sub> Na <sub>0.5</sub> )TiO <sub>3</sub> Single Crystals. <i>Key Engineering Materials</i> , <b>2013</b> , 582, 51-54	0.4	
141	Ferroelectric Properties and Domain Clamping of (Bi <sub>0.5</sub> Na <sub>0.5</sub> )TiO <sub>3</sub> Single Crystals Grown under High-Oxygen-Pressure Atmosphere. <i>Key Engineering Materials</i> , <b>2013</b> , 566, 29-33	0.4	1
140	Crystal Growth and Characterization of (Bi <sub>0.5</sub> Na <sub>0.5</sub> )TiO <sub>3</sub> -BaTiO <sub>3</sub> Single Crystals Obtained by the Top-Seeded Solution Growth Method under High-Pressure Oxygen Atmosphere. <i>Key Engineering Materials</i> , <b>2013</b> , 566, 25-28	0.4	
139	Photocurrent Characteristics of Mn-Doped Barium Titanate Ferroelectric Single Crystals. <i>Japanese Journal of Applied Physics</i> , <b>2013</b> , 52, 09KF03	1.4	16
138	Synchrotron radiation analyses of lattice strain behaviors for rhombohedral Pb(Zn <sub>1/3</sub> Nb <sub>2/3</sub> )O <sub>3</sub> PbTiO <sub>3</sub> single crystals under electric fields. <i>Journal of the Ceramic Society of Japan</i> , <b>2013</b> , 121, 632-637	1	6
137	Observation of a low-symmetry phase in Na <sub>0.5</sub> Bi <sub>0.5</sub> TiO <sub>3</sub> crystals by optical birefringence microscopy. <i>Journal of Applied Crystallography</i> , <b>2012</b> , 45, 444-452	3.8	47
136	Electronic and local structures of Mn-doped BiFeO <sub>3</sub> crystals. <i>Physical Review B</i> , <b>2012</b> , 86,	3.3	53
135	Evaluation methods for properties of nanostructured body <b>2012</b> , 317-383		
134	Laser beam scanning microscope and piezoresponse force microscope studies on domain structured in 001-, 110-, and 111-oriented NaNbO <sub>3</sub> films. <i>Journal of Applied Physics</i> , <b>2012</b> , 112, 052007	2.5	23
133	Clamping of Non-180° Domain Walls in Bi-Based Ferroelectric Single Crystals. <i>Transactions of the Materials Research Society of Japan</i> , <b>2012</b> , 37, 69-72	0.2	
132	(Invited) High-Temperature-Operating Dielectrics of Perovskite Oxides. <i>ECS Transactions</i> , <b>2012</b> , 45, 195-207		4
131	Elastic and Piezoelectric Properties of High-Quality Ferroelectric Bi <sub>4</sub> Ti <sub>3</sub> O <sub>12</sub> Single Crystals. <i>Japanese Journal of Applied Physics</i> , <b>2012</b> , 51, 09LD08	1.4	5
130	Defect Control and Properties in Bismuth Layer Structured Ferroelectric Single Crystals <b>2012</b> , 405-459		3

129	Lattice-Defect Control for High-Performance Bismuth-Based Ferroelectric/Piezoelectric Crystals. <i>Funtai Oyobi Fummatsu Yakin/Journal of the Japan Society of Powder and Powder Metallurgy</i> , <b>2012</b> , 59, 22-28	0.2	
128	High electro-optic kerr effect in (Bi,K,Na)TiO <sub>3</sub> relaxor single crystals. <i>Journal of the Ceramic Society of Japan</i> , <b>2012</b> , 120, 613-615	1	3
127	Elastic and Piezoelectric Properties of High-Quality Ferroelectric Bi <sub>4</sub> Ti <sub>3</sub> O <sub>12</sub> Single Crystals. <i>Japanese Journal of Applied Physics</i> , <b>2012</b> , 51, 09LD08	1.4	3
126	Ferroelectric Properties and Domain Structures of (Bi <sub>0.5</sub> K <sub>0.5</sub> )TiO <sub>3</sub> -BiFeO <sub>3</sub> Ceramics. <i>Transactions of the Materials Research Society of Japan</i> , <b>2011</b> , 36, 285-288	0.2	4
125	Ferroelectric Polarization Properties in High-Performance Bismuth Sodium Titanate Single Crystals. <i>Key Engineering Materials</i> , <b>2011</b> , 485, 7-10	0.4	1
124	Synchrotron Radiation Study on Time-Resolved Tetragonal Lattice Strain of BaTiO <sub>3</sub> under Electric Field. <i>Japanese Journal of Applied Physics</i> , <b>2011</b> , 50, 09NE05	1.4	22
123	Nanoscale Characterization of Domain Structures in Bi <sub>4</sub> Ti <sub>3</sub> O <sub>12</sub> Single Crystals Using Near-Field Raman Spectroscopy. <i>Japanese Journal of Applied Physics</i> , <b>2011</b> , 50, 09NE10	1.4	3
122	Crystal Growth and Characterization of (Bi <sub>0.5</sub> Na <sub>0.5</sub> )TiO <sub>3</sub> BaTiO <sub>3</sub> Single Crystals Obtained by a Top-Seeded Solution Growth Method under High-Pressure Oxygen Atmosphere. <i>Japanese Journal of Applied Physics</i> , <b>2011</b> , 50, 09NE07	1.4	23
121	ENHANCED PIEZOELECTRIC PROPERTIES IN (Bi <sub>0.5</sub> K <sub>0.5</sub> )TiO <sub>3</sub> (Bi <sub>0.5</sub> Na <sub>0.5</sub> )TiO <sub>3</sub> FERROELECTRIC SINGLE CRYSTALS. <i>Journal of Advanced Dielectrics</i> , <b>2011</b> , 01, 63-69	1.3	7
120	High-Performance Ferroelectric Bi <sub>0.5</sub> Na <sub>0.5</sub> TiO <sub>3</sub> Single Crystals Grown by Top-Seeded Solution Growth Method under High-Pressure Oxygen Atmosphere. <i>Ferroelectrics</i> , <b>2011</b> , 414, 24-29	0.6	16
119	Ferroelectric and Piezoelectric Properties of Bi <sub>4</sub> Ti <sub>3</sub> O <sub>12</sub> Single Crystals Grown by Top-Seeded Solution Growth Method at High Oxygen Pressure. <i>Key Engineering Materials</i> , <b>2011</b> , 485, 73-76	0.4	1
118	Synchrotron Radiation Study on Time-Resolved Tetragonal Lattice Strain of BaTiO <sub>3</sub> under Electric Field. <i>Japanese Journal of Applied Physics</i> , <b>2011</b> , 50, 09NE05	1.4	8
117	Crystal Growth and Characterization of (Bi <sub>0.5</sub> Na <sub>0.5</sub> )TiO <sub>3</sub> BaTiO <sub>3</sub> Single Crystals Obtained by a Top-Seeded Solution Growth Method under High-Pressure Oxygen Atmosphere. <i>Japanese Journal of Applied Physics</i> , <b>2011</b> , 50, 09NE07	1.4	7
116	Nanoscale Characterization of Domain Structures in Bi <sub>4</sub> Ti <sub>3</sub> O <sub>12</sub> Single Crystals Using Near-Field Raman Spectroscopy. <i>Japanese Journal of Applied Physics</i> , <b>2011</b> , 50, 09NE10	1.4	2
115	Crystal Growth and Ferroelectric Properties in Bi <sub>0.5</sub> K <sub>0.5</sub> TiO <sub>3</sub> -Bi <sub>0.5</sub> Na <sub>0.5</sub> TiO <sub>3</sub> Crystals. <i>Key Engineering Materials</i> , <b>2010</b> , 445, 7-10	0.4	4
114	Materials Design and Characterization of (Bi <sub>1/2</sub> Na <sub>1/2</sub> )TiO <sub>3</sub> -Bi(Bi)O <sub>3</sub> Ceramics. <i>Key Engineering Materials</i> , <b>2010</b> , 445, 59-62	0.4	2
113	Structural and piezoelectric properties of high-density (Bi <sub>0.5</sub> K <sub>0.5</sub> )TiO <sub>3</sub> BiFeO <sub>3</sub> ceramics. <i>Journal of Applied Physics</i> , <b>2010</b> , 108, 104103	2.5	65
112	Polarization and Piezoelectric Properties of High Performance Bismuth Sodium Titanate Single Crystals Grown by High-Oxygen-Pressure Flux Method. <i>Japanese Journal of Applied Physics</i> , <b>2010</b> , 49, 09MD09	1.4	27

111	Ferroelectric Phase Transition and Photoinduced Cooperative Phenomena in Bi-Layered Perovskite Pb <sub>2</sub> Bi <sub>4</sub> Ti <sub>5</sub> O <sub>18</sub> Ceramics Studied by Brillouin Scattering. <i>Japanese Journal of Applied Physics</i> , <b>2010</b> , 49, 09ME05	1.4	3
110	High-Performance Ferroelectric Bi <sub>4</sub> Ti <sub>3</sub> O <sub>12</sub> Single Crystals Grown by Top-Seeded Solution Growth Method under High-Pressure Oxygen Atmosphere. <i>Japanese Journal of Applied Physics</i> , <b>2010</b> , 49, 09MC06	1.4	27
109	Photoinduced Effect in Quasi-Longrange Ferroelectric Fluctuation on Bismuth Layered Perovskites BaBi <sub>4</sub> Ti <sub>4</sub> O <sub>15</sub> . <i>Ferroelectrics</i> , <b>2010</b> , 411, 44-51	0.6	1
108	Microstructures Related to Ferroelectric Properties in (Bi <sub>0.5</sub> K <sub>0.5</sub> )TiO <sub>3</sub> BiFeO <sub>3</sub> . <i>Japanese Journal of Applied Physics</i> , <b>2010</b> , 49, 09MC05	1.4	17
107	Defect control for polarization switching in BiFeO <sub>3</sub> single crystals. <i>IEEE Transactions on Ultrasonics, Ferroelectrics, and Frequency Control</i> , <b>2010</b> , 57, 2233-6	3.2	24
106	Effect of Mn doping on the leakage current and polarization properties in K <sub>0.14</sub> Na <sub>0.86</sub> NbO <sub>3</sub> ferroelectric single crystals. <i>Journal of the Ceramic Society of Japan</i> , <b>2010</b> , 118, 711-716	1	23
105	Polarization and leakage current properties of bismuth sodium titanate ceramic films deposited by aerosol deposition method. <i>Journal of the Ceramic Society of Japan</i> , <b>2010</b> , 118, 899-902	1	12
104	Oxygen-vacancy-induced 90° domain clamping in ferroelectric Bi <sub>4</sub> Ti <sub>3</sub> O <sub>12</sub> single crystals. <i>Physical Review B</i> , <b>2010</b> , 81,	3.3	86
103	Polarization and piezoelectric properties of grain-oriented ferroelectric Bi <sub>5</sub> FeTi <sub>3</sub> O <sub>15</sub> ceramics prepared by magnetic-field-assisted electrophoretic deposition method. <i>Journal of Electroceramics</i> , <b>2010</b> , 24, 91-96	1.5	6
102	Observation of octahedral tilted in Sr <sub>0.5</sub> TaO <sub>3</sub> prepared by nanosheet processing: An EXAFS study. <i>Journal of Alloys and Compounds</i> , <b>2009</b> , 486, 78-82	5.7	3
101	Ferroelectric Properties and Nano-Scaled Domain Structures in (1-x)BiFeO <sub>3</sub> -xBaTiO <sub>3</sub> (0.33 Ferroelectrics, <b>2009</b> , 385, 6155-6161	0.6	53
100	Electric-field-induced giant strain in Bi <sub>0.5</sub> Na <sub>0.5</sub> TiO <sub>3</sub> -based single crystals: Influence of high-oxygen-pressure annealing. <i>Journal of the Ceramic Society of Japan</i> , <b>2009</b> , 117, 32-36	1	8
99	Behaviors of 90° and 180° Domain Walls under c-axis Polarization Switching in Ferroelectric Bi <sub>4</sub> Ti <sub>3</sub> O <sub>12</sub> Single Crystals. <i>Transactions of the Materials Research Society of Japan</i> , <b>2009</b> , 34, 27-30	0.2	
98	Polarization and piezoelectric properties of high-quality (Bi,Na)TiO <sub>3</sub> crystals grown by high-oxygen-pressure flux method. <i>Transactions of the Materials Research Society of Japan</i> , <b>2009</b> , 34, 31-34	0.2	
97	Crystal structure and Polarization properties of ferroelectric Bi <sub>4</sub> -xLa <sub>x</sub> Ti <sub>3</sub> O <sub>12</sub> single crystals. <i>Journal of the Korean Physical Society</i> , <b>2009</b> , 55, 862-868	0.6	2
96	Crystal Growth and Ferroelectric Properties of Superlattice-Structured Bi <sub>4</sub> Ti <sub>3</sub> O <sub>12</sub> -PbBi <sub>4</sub> Ti <sub>4</sub> O <sub>15</sub> Single Crystals. <i>Key Engineering Materials</i> , <b>2008</b> , 388, 237-240	0.4	
95	Effects of Oxygen Annealing on Dielectric Properties of LuFeCuO <sub>4</sub> . <i>Japanese Journal of Applied Physics</i> , <b>2008</b> , 47, 8464-8467	1.4	10
94	Large electric-field-induced strain in Bi <sub>0.5</sub> Na <sub>0.5</sub> TiO <sub>3</sub> Bi <sub>0.5</sub> K <sub>0.5</sub> TiO <sub>3</sub> solid solution single crystals. <i>Applied Physics Letters</i> , <b>2008</b> , 93, 242903	3.4	46

93	Crystal structure and defect control in Bi <sub>4</sub> Ti <sub>3</sub> O <sub>12</sub> -based layered ferroelectric single crystals <b>2008</b> , 1006-1032		
92	Crystal Growth and Ferroelectric Properties in Bi <sub>0.5</sub> Na <sub>0.5</sub> TiO <sub>3</sub> BaTiO <sub>3</sub> Crystals. <i>Key Engineering Materials</i> , <b>2008</b> , 388, 241-244	0.4	3
91	Grain-Orientation Control of Bi <sub>5</sub> FeTi <sub>3</sub> O <sub>15</sub> Ceramics Prepared by Magnetic-Field-Assisted Electrophoretic Deposition Method. <i>Key Engineering Materials</i> , <b>2008</b> , 388, 205-208	0.4	1
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